DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2002 Nov 12 2003 Feb 26



BGF844

GSM800 EDGE power module

FEATURES

- Typical GSM EDGE performance at a supply voltage of 26 V:
 - Output power = 2.5 W
 - Gain = 30 dB
 - Efficiency = 16%
 - ACPR < -65 dBc at 400 kHz
 - rms EVM < 0.4%
 - peak EVM < 1.2%</p>
- Low distortion to a GSM EDGE signal
- Excellent 2-tone performance
- · Low die temperature due to copper flange
- Integrated temperature compensated bias
- 50 Ω input/output impedance
- Flat gain over frequency band.

APPLICATIONS

- Base station RF power amplifiers in the 869 to 894 MHz frequency range
- GSM, GSM EDGE, multi carrier applications
- Macrocell (driver stage) and Microcell (final stage).

DESCRIPTION

23 W LDMOS power amplifier module for base station amplifier applications in the 869 to 894 MHz band.

QUICK REFERENCE DATA

Typical RF performance at T_{mb} = 25 °C.

MODE OF OPERATION	f (MHz)	V _S (V)	P _L (W)	G _p (dB)	η (%)	ACPR (dBc)	rms EVM (%)
CW	869 to 894	26	23	29	50	-	_
GSM EDGE	869 to 894	26	2.5	30	16	-65(1)	0.4

Note

1. ACPR 400 kHz at 30 kHz resolution bandwidth.

PINNING - SOT365C

PIN	DESCRIPTION
1	RF input
2	VS
3	RF output
Flange	ground



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vs	DC supply voltage	—	30	V
P _D	input drive power	_	100	mW
PL	load power	_	27	W
T _{stg}	storage temperature	-30	+100	°C
T _{mb}	operating mounting base temperature	-20	+90	°C

CHARACTERISTICS

 T_{mb} = 25 °C; V_S = 26 V; P_L = 2.5 W; f = 869 to 894 MHz; Z_S = Z_L = 50 Ω ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{DQ}	quiescent current (pin 2)	$P_D = 0 \text{ mW}$	245	280	320	mA
G _p	power gain		28	30	32	dB
$\Delta G_{p freq}$	gain flatness over frequency range		_	0.2	1	dB
$\Delta G_{p pwr}$	gain flatness over power band	$P_L = 25 \text{ mW}$ up to 2.5 W	-0.8	-0.2	+0.2	dB
G _{OB}	out of band gain	small signal, P _D = 0 dBm; f < 869 MHz, f > 894 MHz	-	-	G _{Pimax} + 1 note 1	dB
VSWR _{in}	input VSWR		_	1.6 : 1	2:1	
IMD _r	reverse intermodulation	$ f_i = f_c \pm 200 \text{ kHz}; \\ P_{carrier} = 2.5 \text{ W}; \\ P_{interference} = -40 \text{ dBc}; $	_	-67	-64	dBc
H ₂	second harmonic		_	-38	-34	dBc
H ₃	third harmonic		_	-61	-58	dBc
	stability	VSWR \leq 3 : 1 through all phases; V _{S2} = 25 to 28 V	all spurio below de	us outputs sired signa	more than 6	0 dB
	ruggedness	VSWR = 10 : 1 through all phases; P _L = 5 W	no degradation in output power			
EDGE (PL =	EDGE (P _L = 2.5 W average)					
η	efficiency		13	16	-	%
SR200	spectral regrowth;	200 kHz	_	-36	-35	dBc
SR400	EDGE GSM signal	400 kHz	-	-65	-63	dBc
SR600		600 kHz	_	-75	-73	dBc
EVM _{rms}	rms EDGE signal distortion		-	0.4	1.2	%
EVMM	peak EDGE signal distortion		-	1.2	4	%
Intermodulation distortion (P _L = 2.5 W average)						
d ₃	third order intermodulation	carrier spacing = 200 kHz	_	-45	-	dBc
d ₅	fifth order intermodulation		_	-52	-	dBc
d ₇	seventh order intermodulation		_	-60	_	dBc

Note

1. G_{Pi} is small signal in-band gain.

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MBL773

6

6

8

10

P_{L (AV)} (W)

12

Fig.3

8

10

 $P_{L(AV)}(W)$

MBL775

12



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48

η (%)

36

24

12

0

0 ^S11

(dB)

-6

-12

-18

-24

-30



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MOUNTING RECOMMENDATIONS

General

LDMOST base station modules are manufactured with the dies directly mounted onto a copper flange. The matching and bias circuit components are mounted on a printed-circuit board (PCB), which is also soldered onto the copper flange. The dies and the PCB are encapsulated in a plastic cap, and pins extending from the module provide a means of electrical connection. This construction allows the module to withstand a limited amount of flexing, although bending of the module is to be avoided as much as possible. Mechanical stress can occur if the bottom surface of the module and the surface of the amplifier casing (external heatsink) are not mutually flat. This, therefore, should be a consideration when mounting the module in the amplifier. Another cause of mechanical stress can arise from thermal mismatch after soldering of the pins. Precautions should be taken during soldering, and efforts made to ensure a good thermal contact between the flange and the external heatsink.

External heatsink (amplifier casing)

The module should always be mounted on a heatsink with a low thermal resistance to keep the module temperature as low as possible. The mounting area of the heatsink should be flat and free from burrs and loose particles. We recommend a flatness for the mounting area of between 50 μ m concave and 50 μ m convex. The 50 μ m concave value is to ensure optimal thermal behaviour, while the 50 μ m convex value is intended to limit mechanical stress due to bending.

In order to ensure optimal thermal behaviour, the use of thermal compound is recommended when mounting the module onto the amplifier external heatsink.

The following recommended thermal compounds have a thermal conductivity of >0.5 W/mK:

- WPS II (silicone-free) from Austerlitz-Electronics
- · Comp. Trans. from KF
- 340 from Dow Corning
- Trans-Heat from E. Friis-Mikkelsen.

The use of thermal pads instead of thermal compound is not recommended as the pads may not maintain a uniform flatness over a period of time.

Mounting

PREPARATION

Ensure that the surface finishes are free from burrs, dirt and grease.

CAUTION

During the following procedures ESD precautions should be taken to protect the device from electrostatic damage.

PROCEDURE

- Apply a thin, evenly spread layer of thermal compound to the module flange bottom surface. Excessive use of thermal compound may result in increased thermal resistance and possible bending of the of the flange. Too little thermal compound will result in an increase in thermal resistance.
- 2. Take care that there is some space between the cap and the PCB. Bring the module into contact with the external heatsink casing, ensuring that there is sufficient space for excessive thermal compound to escape.
- 3. Carefully align the module with the heatsink casing mounting holes, and secure with two 3 mm bolts and two flat washers. Initially tighten the bolts to "finger tight" (approximately 0.05 Nm). Using a torque wrench, tighten each bolt in alternating steps to a final torque of 0.4 Nm.
- After the module is secured to the casing, the module leads may be soldered to the PCB. The leads are for electrical connection only, and should not be used to support the module at any time in the assembly process.

A soldering iron may be used up to a temperature of 250 °C for a maximum of 10 seconds. Avoid contact between the soldering iron and the plastic cap.

Electrical connections

The main ground path of all modules is via the flange. It is therefore important that the flange is well grounded and that return paths are kept as short as possible. An incorrectly grounded flange can result in a loss of output power or in oscillation.

The RF input and output of the module are designed for 50 Ω connections.

Incoming inspection

When incoming inspection is performed, use a properly designed test fixture to avoid excessive mechanical stress and to ensure optimal RF performance. Philips can deliver dedicated test fixtures on request.

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APPLICATION INFORMATION



List of components (see Figs 10 and 11)

COMPONENT	DESCRIPTION	VALUE	CATALOGUE NUMBER
C1, C3	multilayer X7R ceramic chip capacitor	100 nF; 50 V	
C2, C5	tantalum SMD capacitor	10 μF; 35 V	
C4	electrolytic capacitor	100 μF; 35 V	
L1	grade 4S2 Ferroxcube bead		4330 030 36300
R1	metal film resistor		2322 195 13109
Z ₁ , Z ₂	stripline; note 1	50 Ω	

Note

1. The striplines are on a double copper-clad printed-circuit board (RO5880) with ϵ_r = 2.2 and thickness = 0.79 mm.

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PACKAGE OUTLINE



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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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